

Features

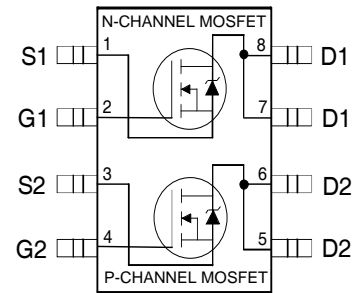
N-Ch:

- $V_{DS} (V) = 20V$
- $R_{DS(ON)} < 53m\Omega$ ($V_{GS} = 4.5V$)
- $R_{DS(ON)} < 70m\Omega$ ($V_{GS} = 2.7V$)

P-Ch:

- $V_{DS} (V) = -20V$
- $R_{DS(ON)} < 100m\Omega$ ($V_{GS} = -4.5V$)
- $R_{DS(ON)} < 140m\Omega$ ($V_{GS} = -2.7V$)

- Generation V Technology Ultra
- Low On-Resistance
- Dual N and P Channel Mosfet
- Surface Mount
- Dynamic dv/dt Rating
- Fast Switching
- Lead-Free



SOP-8

Description

The so-8 has been modified through a customized leadframe for enhanced thermal characteristics and multiple die capability making it ideal in a variety of power applications. With these improvements, multiple devices can be used in an application with dramatically reduced board space. The package is designed for vapor phase, infra red, or wave soldering techniques. Power dissipation of greater than 0.8W is possible in a typical PCB mount application.

Absolute Maximum Ratings

	Parameter	Max.		Units
		N-Channel	P-Channel	
$I_D @ T_A = 25^\circ C$	10 Sec. Pulse Drain Current, $V_{GS} @ 4.5V$	5.7	-4.7	A
$I_D @ T_A = 25^\circ C$	Continuous Drain Current, $V_{GS} @ 4.5V$	5.2	-4.3	
$I_D @ T_A = 70^\circ C$	Continuous Drain Current, $V_{GS} @ 4.5V$	4.1	-3.4	
I_{DM}	Pulsed Drain Current ①	21	-17	
$P_D @ T_A = 25^\circ C$	Power Dissipation	2.0		W
	Linear Derating Factor	0.016		W/°C
V_{GS}	Gate-to-Source Voltage	± 12		V
dv/dt	Peak Diode Recovery dv/dt ②	5.0	-5.0	V/ns
T_J, T_{STG}	Junction and Storage Temperature Range	-55 to + 150		°C

Thermal Resistance Ratings

	Parameter	Typ.	Max.	Units
$R_{\theta JA}$	Maximum Junction-to-Ambient ③		62.5	°C/W

Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Parameter	Min.	Typ.	Max.	Units	Conditions
V _{(BR)DSS}	N-Ch 20 P-Ch -20			V	V _{GS} = 0V, I _D = 250μA V _{GS} = 0V, I _D = -250μA
ΔV _{(BR)DSS} /ΔT _J	N-Ch P-Ch	0.044 -0.012		V/°C	Reference to 25°C, I _D = 1mA Reference to 25°C, I _D = -1mA
R _{DS(ON)}	N-Ch P-Ch		53 70 100 140	mΩ	V _{GS} = 4.5V, I _D = 2.6A ③ V _{GS} = 2.7V, I _D = 2.2A ③ V _{GS} = -4.5V, I _D = -2.2A ③ V _{GS} = -2.7V, I _D = -1.8A ③
V _{GS(th)}	N-Ch P-Ch	0.70 -0.70		V	V _{DS} = V _{GS} , I _D = 250μA V _{DS} = V _{GS} , I _D = -250μA
g _{fs}	N-Ch P-Ch	8.30 4.00		S	V _{DS} = 15V, I _D = 2.6A ③ V _{DS} = -15V, I _D = -2.2A ③
I _{DSS}	N-Ch P-Ch N-Ch P-Ch		1.0 -1.0 25 -25	μA	V _{DS} = 16V, V _{GS} = 0V V _{DS} = -16V, V _{GS} = 0V V _{DS} = 16V, V _{GS} = 0V, T _J = 125°C V _{DS} = -16V, V _{GS} = 0V, T _J = 125°C
I _{GSS}	N-P		±100		V _{GS} = ±12V
Q _g	N-Ch P-Ch		20 22	nC	N-Channel I _D = 2.6A, V _{DS} = 16V, V _{GS} = 4.5V
Q _{gs}	N-Ch P-Ch		2.2 3.3	nC	P-Channel ③ I _D = -2.2A, V _{DS} = -16V, V _{GS} = -4.5V
Q _{gd}	N-Ch P-Ch		8.0 9.0	nC	
t _{d(on)}	N-Ch P-Ch		9.0 8.4	ns	N-Channel V _{DD} = 10V, I _D = 2.6A, R _G = 6.0Ω, R _D = 3.8Ω
t _r	N-Ch P-Ch		42 26	ns	
t _{d(off)}	N-Ch P-Ch		32 51	ns	P-Channel ③ V _{DD} = -10V, I _D = -2.2A, R _G = 6.0Ω, R _D = 4.5Ω
t _f	N-Ch P-Ch		51 33	ns	
L _D	N-P		4.0	nH	Between lead tip and center of die contact
L _S	N-P		6.0	nH	
C _{iss}	N-Ch P-Ch		660 610	pF	N-Channel V _{GS} = 0V, V _{DS} = 15V, f = 1.0MHz
C _{oss}	N-Ch P-Ch		280 310	pF	P-Channel ③ V _{GS} = 0V, V _{DS} = -15V, f = 1.0MHz
C _{rss}	N-Ch P-Ch		140 170	pF	

Source-Drain Ratings and Characteristics

Parameter	Min.	Typ.	Max.	Units	Conditions
I _S	N-Ch P-Ch		2.5 -2.5	A	
I _{SM}	N-Ch P-Ch		21 -17	A	
V _{SD}	N-Ch P-Ch		1.0 -1.0	V	T _J = 25°C, I _S = 1.8A, V _{GS} = 0V ③ T _J = 25°C, I _S = -1.8A, V _{GS} = 0V ③
t _{rr}	N-Ch P-Ch		29 44 56 84	ns	N-Channel T _J = 25°C, I _F = 2.6A, di/dt = 100A/μs
Q _{rr}	N-Ch P-Ch		22 33 71 110	nC	P-Channel ③ T _J = 25°C, I _F = -2.2A, di/dt = 100A/μs
t _{on}	N-P				Intrinsic turn-on time is negligible (turn-on is dominated by L _S +L _D)

Notes:

- ① Repetitive rating; pulse width limited by max. junction temperature. (See fig. 23)
- ② N-Channel I_{SD} ≤ 2.6A, di/dt ≤ 100A/μs, V_{DD} ≤ V_{(BR)DSS}, T_J ≤ 150°C
P-Channel I_{SD} ≤ -2.2A, di/dt ≤ 50A/μs, V_{DD} ≤ V_{(BR)DSS}, T_J ≤ 150°C
- ③ Pulse width ≤ 300μs; duty cycle ≤ 2%.
- ④ Surface mounted on FR-4 board, t ≤ 10sec.

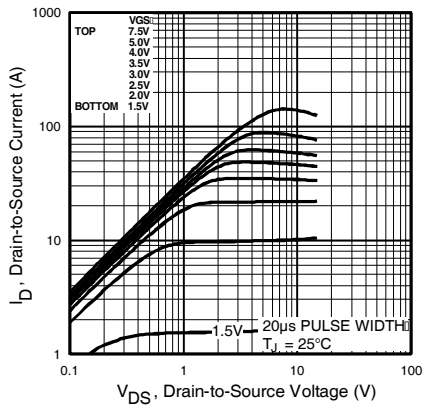


Fig 1. Typical Output Characteristics

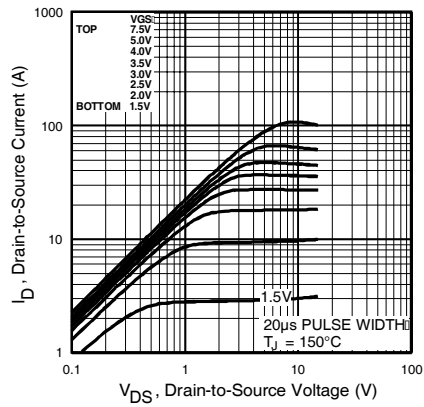


Fig 2. Typical Output Characteristics

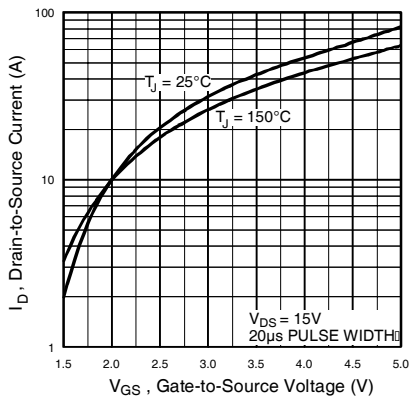


Fig 3. Typical Transfer Characteristics

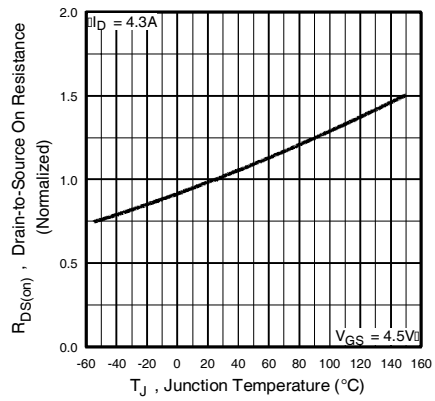


Fig 4. Normalized On-Resistance Vs. Temperature

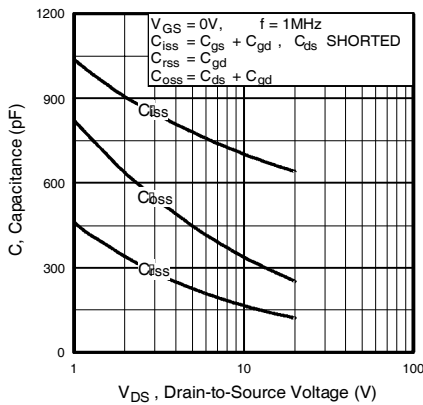


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

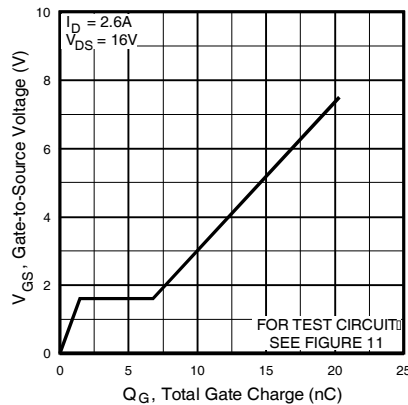


Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage

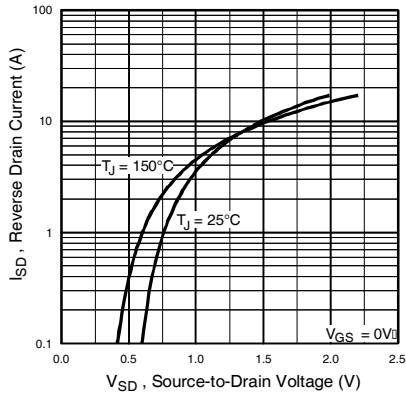


Fig 7. Typical Source-Drain Diode Forward Voltage

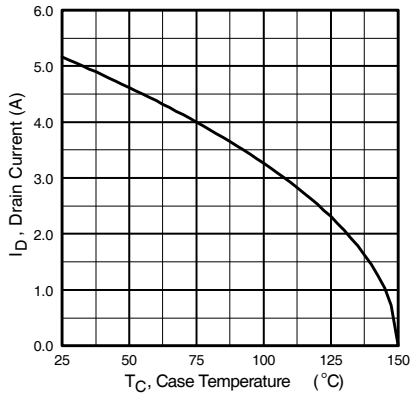


Fig 9. Maximum Drain Current Vs. Ambient Temperature

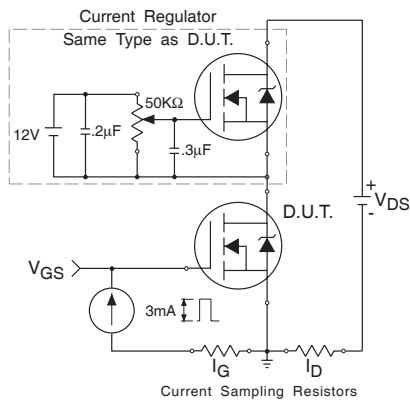


Fig 11a. Gate Charge Test Circuit

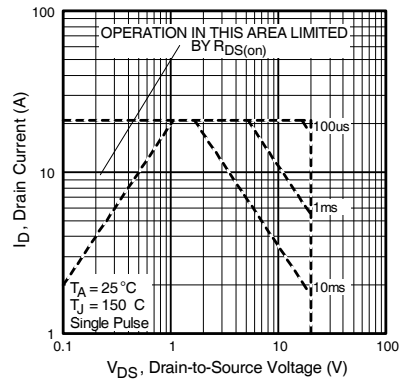


Fig 8. Maximum Safe Operating Area

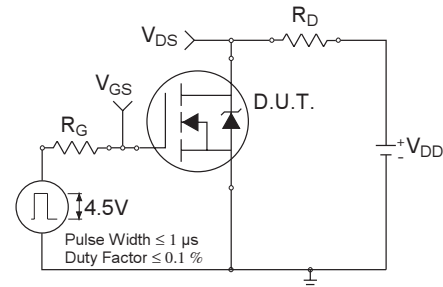


Fig 10a. Switching Time Test Circuit

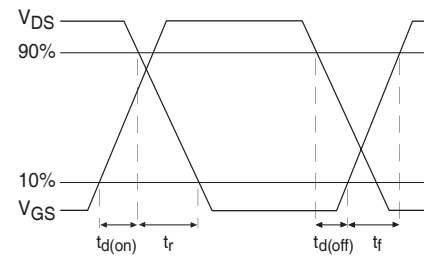


Fig 10b. Switching Time Waveforms

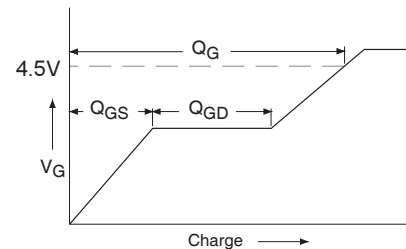


Fig 11b. Basic Gate Charge Waveform

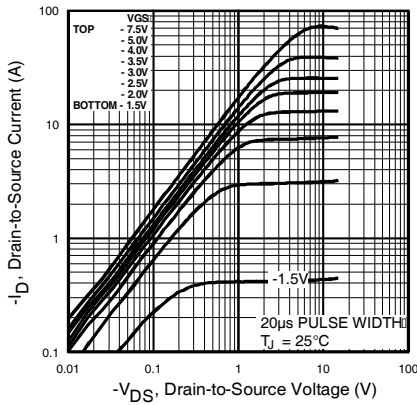


Fig 12. Typical Output Characteristics

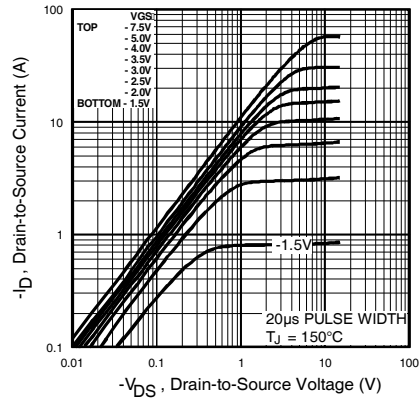


Fig 13. Typical Output Characteristics

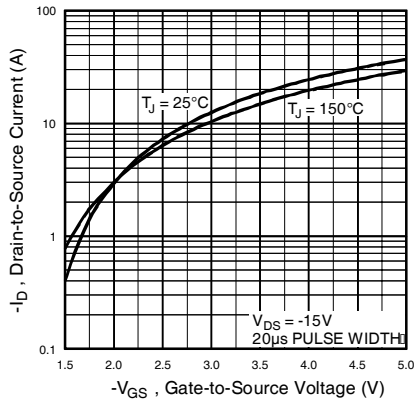


Fig 14. Typical Transfer Characteristics

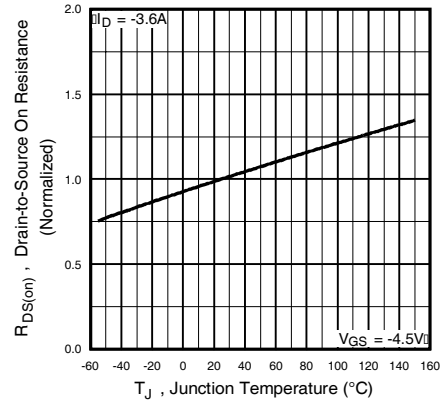


Fig 15. Normalized On-Resistance Vs. Temperature

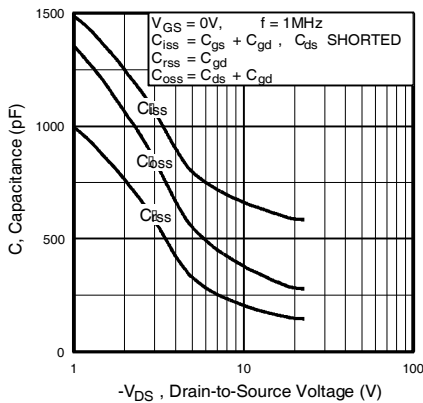


Fig 16. Typical Capacitance Vs. Drain-to-Source Voltage

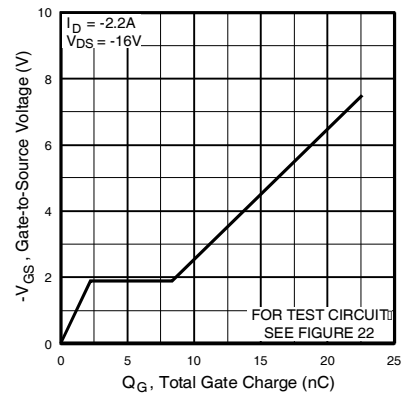


Fig 17. Typical Gate Charge Vs. Gate-to-Source Voltage

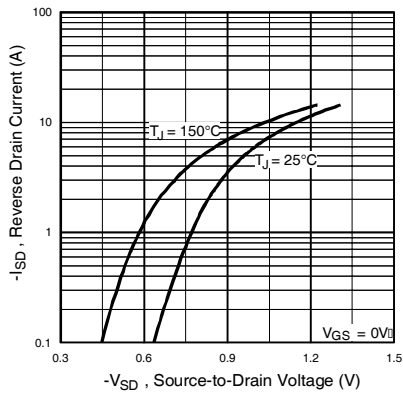


Fig 18. Typical Source-Drain Diode Forward Voltage

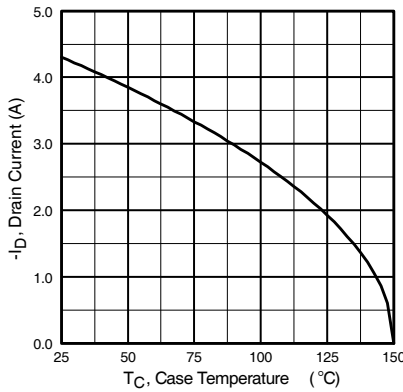


Fig 20. Maximum Drain Current Vs. Ambient Temperature

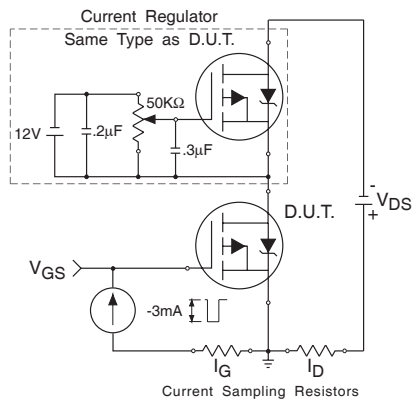


Fig 22a. Gate Charge Test Circuit

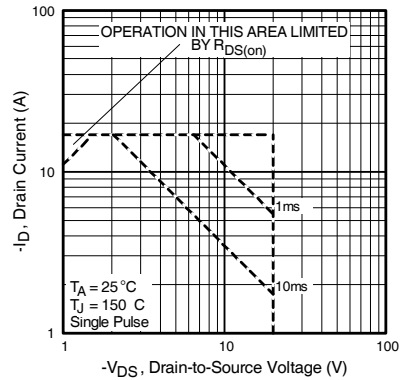


Fig 19. Maximum Safe Operating Area

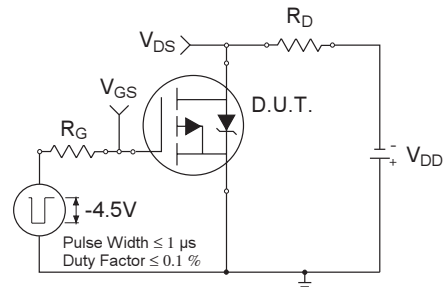


Fig 21a. Switching Time Test Circuit

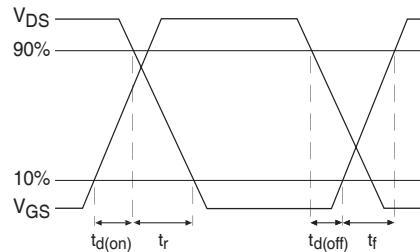


Fig 21b. Switching Time Waveforms

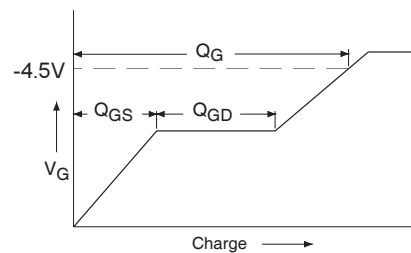


Fig 22b. Basic Gate Charge Waveform

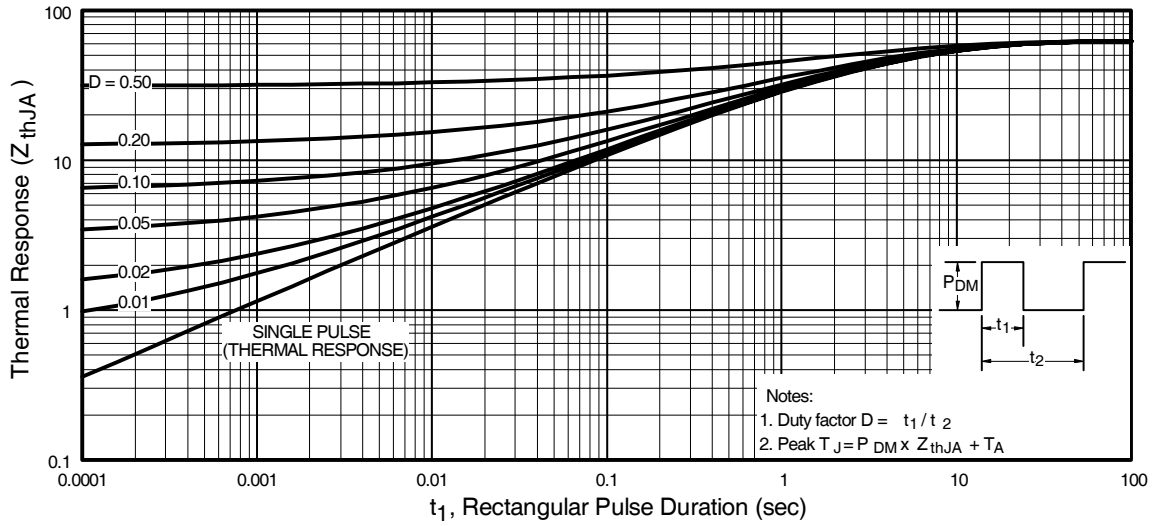
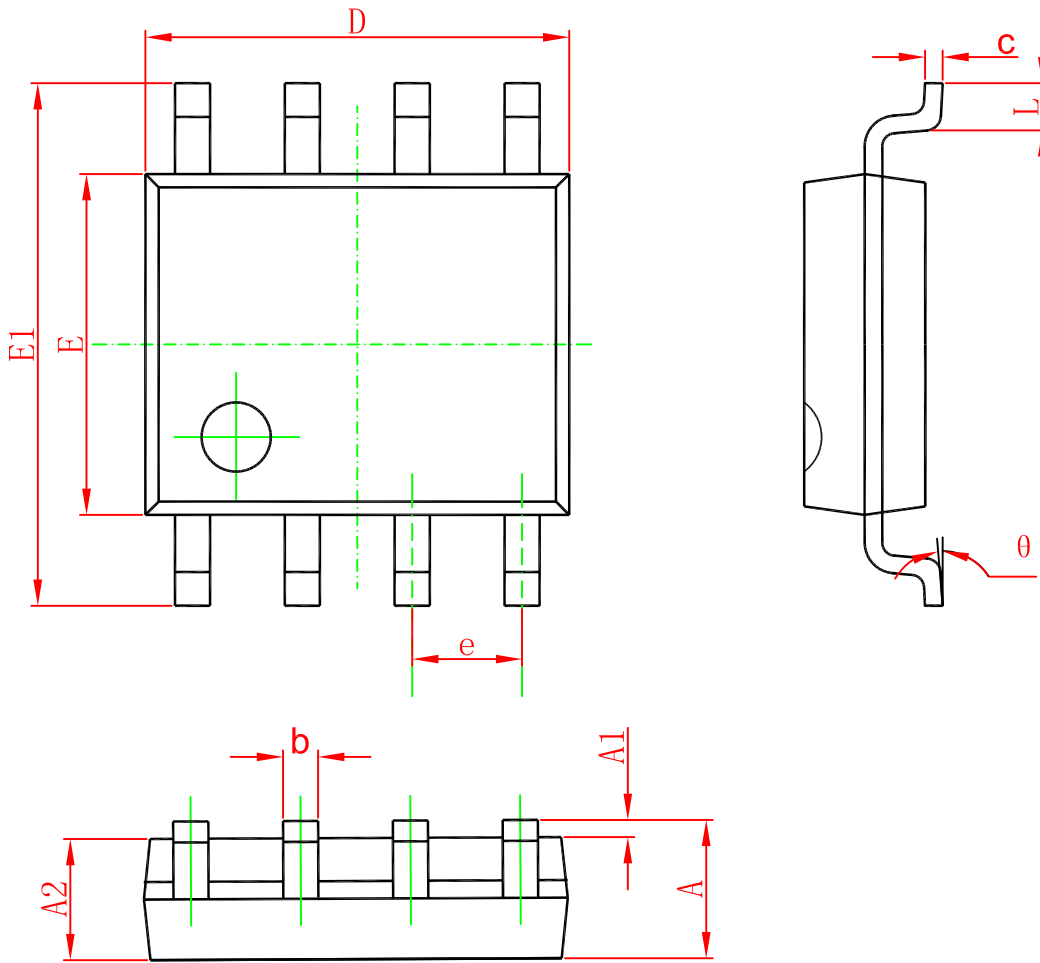


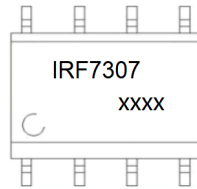
Fig 23. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient

SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

Marking



Ordering information

Order code	Package	Baseqty	Deliverymode
IRF7307TR	SOP-8	3000	Tape and reel